


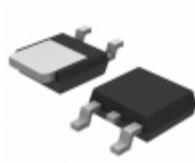



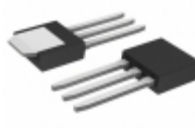
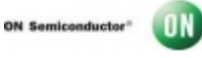
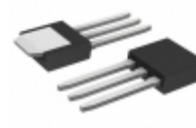
	<h2 style="color: red;">NTD40N03RT4G</h2>	
	Hersteller-Teilenummer:	NTD40N03RT4G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET N-CH 25V 7.8A DPAK
	Datenblätter:	 NTD40N03RT4G.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 74096 pcs Stock Available.
	Liefern von:	Hong Kong
Image may be representation. See specs for product details.	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen	
Teilenummer	NTD40N03RT4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 25V 7.8A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	74096 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.5W (Ta), 50W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	7.8A (Ta), 32A (Tc)
Rds On (Max) @ Id, Vgs	16.5 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	5.78nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	584pF @ 20V
Verpackung	Tape & Reel (TR)



















































NTD40N03RT4G ist neu im Original, Suche NTD40N03RT4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD40N03RT4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD40N03RT4G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD4302-1 MOTOROL MOTOROL TO-251</p>	 <p>NTD4302 AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 8.4A DPAK</p>	 <p>NTD4302-001 ON NTD4302-001 ON</p>	 <p>NTD40N03R-1 ON NTD40N03R-1 ON</p>
 <p>NTD40N03RT4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.8A DPAK</p>	 <p>NTD40N03R-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.8A IPAK</p>	 <p>NTD40N05 AMI Semiconductor / ON Semiconductor NTD40N05 ON</p>	 <p>NTD40N03R-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 45A IPAK</p>

heiße Teile

Mehr

 NTD3055L170T4G	 NTD3055LT4G	 NTD3055VLT4G	 D NTD30N02G	 NTD30N02T4
 NTD30N02T4G	 NTD30N06RT4	 D NTD30N06T4G	 NTD32N06-001	 NTD32N06-1G
 NTD32N06G	 NTD32N06L	 NTD32N06L-001	 NTD32N06L-1G	 NTD32N06LG
 D NTD32N06LT4G	 NTD32N06T4G	 NTD3808NT4G	 NTD3813NT4G	 NTD3817NT4G
 NTD40N03R	 NTD40N03R-1	 NTD40N03R-1G	 NTD40N03RG	 NTD40N03RT4
 NTD4302-001	 NTD4302-001G	 D NTD4302-1G	 NTD4302G	 NTD4302T4
 NTD4302T4G	 D NTD4804N	 NTD4804NT4G	 NTD4805N	 NTD4805N-1G
 NTD4805NT4G	 NTD4806N	 NTD4806N-35G	 NTD4806NA-35G	 NTD4806NG
 NTD4806NT4G	 NTD4808N	 NTD4808N-35G	 D NTD4808NG	 NTD4808NT4G
 NTD4809N-35G	 NTD4809NAT4G	 NTD4809NH-35G	 NTD4809NHG	 NTD4809NHT4G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited